# 1N914UR, 1N4148UR-1, 1N4531UR

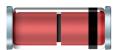


## Silicon Switching Diode

Rev. V1

### **Features**

- Available in JAN, JANTX, and JANTXV per MIL-PRF-19500/116
- Metallurgically Bonded
- Hermetically Sealed
- Double Plug Construction



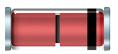
### **Maximum Ratings**

Operating & Storage Temperature: -65°C to +175°C

Operating Current: 200 mA @ T<sub>A</sub> = +25°C

Derating Factor: 1.14 mA/ $^{\circ}$ C above  $T_A$  = +25 $^{\circ}$ C Surge Current A: 2.00 A,

sinewave, Pw = 8.3 ms



### Electrical Specifications @ $T_A = +25$ °C (unless otherwise specified)

JEDEC TYPE#	V <sub>BR</sub> @ 100 μA	V <sub>RWM</sub>	I <sub>O(PCB)</sub> T <sub>A</sub> = +75°C	V <sub>F1</sub> I <sub>F</sub> = 10 mA	V <sub>F2</sub> I <sub>F</sub> = 100* mA	T <sub>rr</sub> <sup>4</sup>	I <sub>R1</sub> @ 20 Vdc	I <sub>R2</sub> @ 75 Vdc	I <sub>R3</sub> @ 20 Vdc T <sub>A</sub> =150°C	I <sub>R4</sub> @ 75 Vdc T <sub>A</sub> =150°C	Capacitance @ 0 V	Capacitance @1.5 V
	Volts	Volts (pk)	mA	Vdc	Vdc	nsec	nA	nA	μΑ	μА	pF	pF
1N914UR	100	75	200	0.8	1.2	5	25	500	35	75	4.0	2.8
1N4148UR-1	100	75	200	0.8	1.2	5	35	500	35	75	4.0	2.8
1N4531UR	100	75	200	0.8	1.2	5	35	500	35	75	4.0	2.8

<sup>4.</sup>  $I_F = I_R = 10 \text{ mA}, R_L = 100 \text{ ohms}.$ 

### **Thermal Characteristics**

Parameter	Absolute Maximum
R <sub>e,JEC</sub> (2)	100°C/W

<sup>1)</sup> For temperature-current derating curves, see figures 9 and 10.

(2) See figures 11, 12, and 13 of MIL-PRF-19500/116 for thermal impedance curves.

For 1N914  $V_{F2}$  is measured at  $I_F = 50$  mA dc

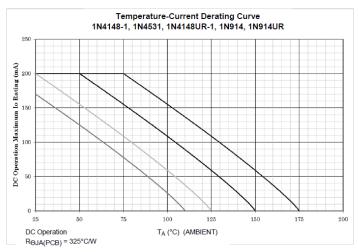
<sup>(3)</sup> T<sub>A</sub> = +75°C for MELF (UR) devices on printed circuit board. PCB = FR4- .0625 inch (1.59 mm) 1 layer,1 oz Cu, horizontal, in still air; pads for (UR) device = .061 inch (1.55 mm) x .105 inch (2.67 mm).



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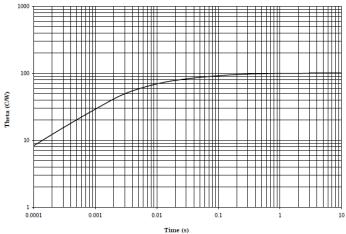
### **Graphs**



- 1. This is the true inverse of the worst case thermal resistance value. All devices are capable of operating at ≤ T<sub>J</sub> specified on this curve. Any parallel line to this curve will intersect the appropriate current for the desired maximum Ti allowed.
- 2. Derate design curve constrained by the maximum junction temperature ( $T_J \le +175^{\circ}C$ ) and current rating specified. (See 1.3.)

  3. Derate design curve chosen at  $T_J \le +150^{\circ}C$ , where the maximum temperature of electrical test is performed.
- 4. Derate design curves chosen at  $T_J \le +125^{\circ}C$ , and  $110^{\circ}C$  to show current rating where most users want to limit T<sub>J</sub> in their application.

### **Maximum Thermal Impedance Plots** 1N4148UR-1, 1N4531UR, 1N914UR DO-213AA TEC = 25°C



 $R_{\theta JEC} = 100^{\circ}C/W$ 

NOTE:  $Z_{\theta JX} = 70^{\circ}$ C/W maximum at  $t_H = 10$  ms.

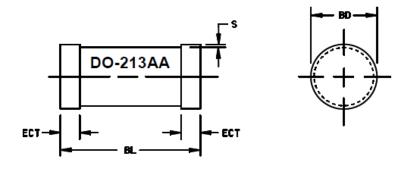
FIGURE 12. Thermal impedance (MELF surface mount)



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## **Outline Drawing (DO-213AA)**



	Dimensions							
Symbol	Inc	hes	Millimeters					
	Min	Max	Min	Max				
BD	.063	.067	1.60	1.70				
BL	.130	.146	3.30	3.71				
ECT	.016	.022	0.41	0.56				
S	.001		0.03					

### NOTES:

- 1. Dimensions are in inches. Millimeters are given for general information only.
- 2. Dimensions are pre-solder dip.
- 3. Referencing to dimension S, minimum clearance of glass body to mounting surface on all orientations.
- In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

TYPES 1N914UR, 1N4148UR-1, AND 1N4531UR.

FIGURE 2. Physical dimensions (DO-213AA).

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